

SANYO Semiconductors DATA SHEET

P-Channel Silicon MOSFET

ECH8305— General-Purpose Switching Device Applications

Features

- · Low ON-resistance.
- · 4V drive.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		-60	V
Gate-to-Source Voltage	VGSS		±20	V
Drain Current (DC)	ΙD		-4	Α
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	-20	Α
Allowable Power Dissipation	PD	Mounted on a ceramic board (900mm ² X0.8mm)	1.6	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

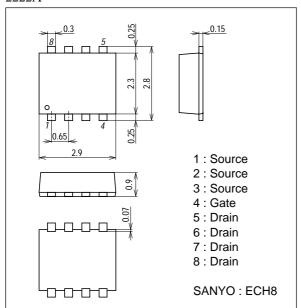
Parameter	Symbol	Conditions		Ratings		
			min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	I _D =-1mA, V _G S=0	-60			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =-60V, V _{GS} =0			-1	μΑ
Gate-to-Source Leakage Current	IGSS	V _{GS} =±16V, V _{DS} =0			±10	μΑ
Cutoff Voltage	VGS(off)	V _{DS} =-10V, I _D =-1mA	-1.0		-2.4	V
Forward Transfer Admittance	yfs	V _{DS} =-10V, I _D =-2A	4.3	7.3		S
Static Drain-to-Source On-State Resistance	R _{DS} (on)1	I _D =-2A, V _G S=-10V		62	85	mΩ
	R _{DS} (on)2	I _D =-1A, V _G S=-4V		82	115	mΩ
Input Capacitance	Ciss	V _{DS} =-20V, f=1MHz		1680		pF
Output Capacitance	Coss	V _{DS} =-20V, f=1MHz		122		pF
Reverse Transfer Capacitance	Crss	V _{DS} =-20V, f=1MHz		102		pF
Turn-ON Delay Time	td(on)	See specified Test Circuit.		15		ns
Rise Time	t _r	See specified Test Circuit.		17		ns
Turn-OFF Delay Time	td(off)	See specified Test Circuit.		185		ns
Fall Time	tf	See specified Test Circuit.		65		ns
Total Gate Charge	Qg	V _{DS} =-30V, V _{GS} =-10V, I _D =-4A		34		nC
Gate-to-Source Charge	Qgs	V _{DS} =-30V, V _{GS} =-10V, I _D =-4A		4.5		nC
Gate-to-Drain "Miller" Charge	Qgd	V _{DS} =-30V, V _{GS} =-10V, I _D =-4A		5.8		nC
Diode Forward Voltage	V _{SD}	I _S =-4A, V _G S=0		-0.81	-1.2	V

Marking : JG

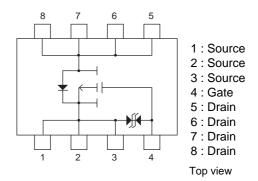
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Package Dimensions

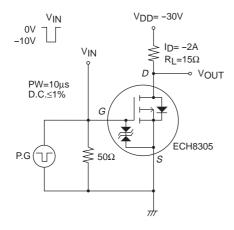
unit : mm 2222A

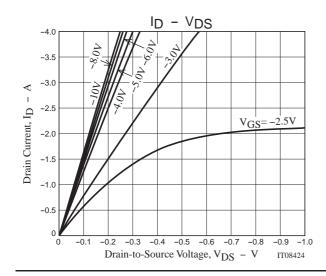


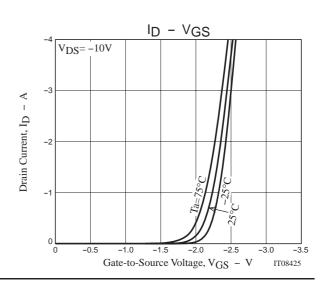
Electrical Connection

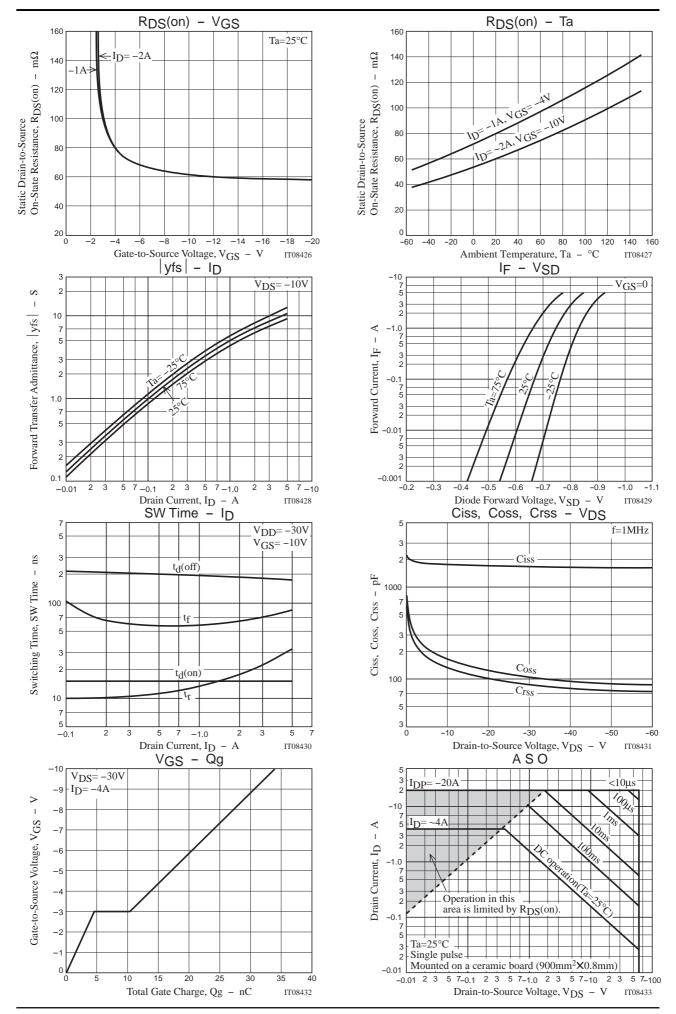


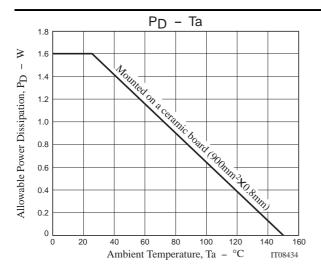
Switching Time Test Circuit











Note on usage: Since the ECH8305 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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